



BRAINWARE UNIVERSITY

Term End Examination 2018 - 19

Programme – B.Sc. (Honours) in Computer Science

Course Name – Introduction to Electrical Circuits and Basic Electronics I

Course Code – EC101/ BCSG101

(Semester – 1)

Time allotted: 3 Hours

Full Marks: 70

[The figure in the margin indicates full marks. Candidates are required to give their answers in their own words as far as practicable.]

Group –A

(Multiple Choice Type Question)

10 x 1 = 10

1. *Choose the correct alternative from the following*

- (i) If w is the width of the depletion region in p-n junction, the transition capacitance is proportional to
- | | |
|----------|------------|
| a. w | b. w^2 |
| c. $1/w$ | d. $1/w^2$ |
- (ii) Ripple factor of half wave rectifier is
- | | |
|---------|---------|
| a. 0.52 | b. 1.21 |
| c. 0.48 | d. 1 |
- (iii) The I-V characteristics of tunnel diode exhibit
- | | |
|---|---|
| a. current-controlled negative resistance | b. voltage-controlled negative resistance |
| c. temperature-controlled positive resistance | d. current-controlled positive resistance |
- (iv) In a junction transistor, recombination of electrons and holes occurs in
- | | |
|--------------------------|--------------------------|
| a. base region only | b. emitter region only |
| c. collector region only | d. all the three regions |

- (v) If $\alpha = 0.98$, then β is equal to
- | | |
|---------|--------|
| a. 0.49 | b. 49 |
| c. 50 | d. 0.5 |
- (vi) The diffusion capacitance of p-n junction diode
- | | |
|--|--|
| a. increases with forward bias voltage | b. decreases exponentially with forward bias voltage |
| c. decreases with forward bias voltage | d. increases with forward bias voltage |
- (vii) Kirchhoff's voltage law is used for
- | | |
|--------------------------------------|-------------------|
| a. loop analysis | b. nodal analysis |
| c. finding out equivalent resistance | d. none of these |
- (viii) In a linear circuit, the superposition principle can be applied to calculate
- | | |
|----------------------|-------------------------------|
| a. voltage and power | b. voltage and current |
| c. current and power | d. voltage, current and power |
- (ix) The transformer turns ratio determines
- | | |
|--|--|
| a. all | b. the ratio of primary and secondary currents |
| c. the ratio of secondary and primary voltages | d. the reflected impedance |
- (x) Four capacitors each of $40 \mu\text{F}$ are connected in parallel, the equivalent capacitance of the system will be
- | | |
|----------------------|---------------------|
| a. $160 \mu\text{F}$ | b. $10 \mu\text{F}$ |
| c. $40 \mu\text{F}$ | d. $5 \mu\text{F}$ |

Group – B

(Short Answer Type Questions)

3 x 5 = 15

Answer any *three* from the following

2. Explain the action of Zener diode, illustrating both avalanche break no gap down and Zener break down.

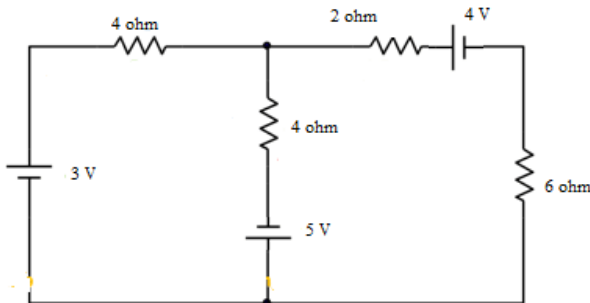
5

3. Find out the relation between α and β for a transistor, where notations have their usual meanings. Find α and I_C of a transistor with $\beta = 49$ and $I_E = 12 \text{ mA}$.

3+2

4. Find current in 6 ohm resistor using Norton's theorem for the network shown in figure below:

5

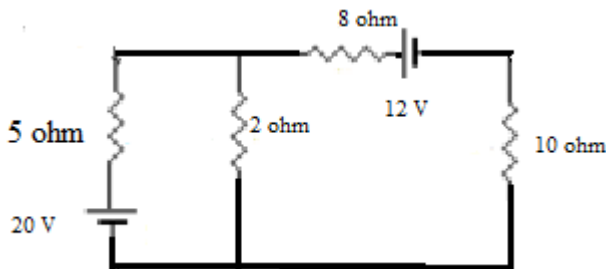


5. 27 spherical drops, each of same size, are charged at 220 V each. They coalesce to form a bigger spherical drop. Calculate the potential of the bigger drop.

5

6. For the circuit shown in figure, calculate the current in the 10 ohm resistance. Use Thevenin's theorem.

5



Group – C

(Long Answer Type Questions)

3 x 15 = 45

Answer any *three* from the following

7. (a) Derive an expression for conductivity of an extrinsic semi-conductor in terms of carrier concentration.
- (b) At 300K the intrinsic concentration of silicon is $1.5 \times 10^{16} \text{ m}^{-3}$. If the electron and the hole mobilities are $0.13 \text{ m}^2/(\text{Vs})$ and $0.05 \text{ m}^2/(\text{Vs})$ respectively, determine the intrinsic conductivity and resistivity of silicon at 300K.

5

5

- (c) Draw the circuit diagram of a full wave rectifier using p-n junction diodes and explain its operation. 5
8. (a) Explain the term resonance in electrical circuits subjected to alternating voltage. Find the condition for resonance in case of series L-C-R circuit fed by alternating voltage. In series L-C-R circuit at resonance, potential difference across which of L, C and R equal the applied voltage? Justify. 2+5+2
- (b) An alternating voltage 100 V, 1000 Hz is applied to series combination of a 100 Ω resistor and 10 μ F capacitor. Calculate circuit current, potential difference across the capacitor and potential difference across the resistor. 6
9. (a) What is quality factor (Q) for an a.c circuit? Prove that in case of series LCR circuit, the quality factor (Q) is given by $Q = \frac{1}{R} \sqrt{\frac{L}{C}}$ 2+3
- (b) Illustrate wattless current in ac circuit. What is its importance? 4+1
- (c) An alternating emf of 14 volt (r.m.s) is applied to a circuit containing an inductance of 0.2025 H, a capacitance of 50 μ F and a resistance of 0.2 Ω connected in series. Determine i) the resonant frequency ii) the potential difference across the inductance and iii) the Q-factor. 2+2+1
10. (a) Show that when a charged capacitor is allowed to discharge through a resistor, the decay of charge is exponential. 5
- (b) What is the time constant? Draw q vs t graph for two time constants λ_2 and λ_1 when $\lambda_2 > \lambda_1$. What is the unit of time constant? 5
- (c) When a charged capacitor of 2 μ F is discharged through a resistance, it losses 50% of the charge in 5 min. Find the unknown resistance. Neglect natural leakage. 5
11. (a) Why n-p-n and p-n-p transistors are called bipolar transistors? 2
- (b) Discuss the input and output characteristics of npn transistor in CB configuration. What is early effect? 6+2
- (c) If $\beta=16.5$, $I_E=1.8$ mA and $I_{CO}=12$ μ A, calculate I_c and I_B when the transistor is used in CE configuration. 5
